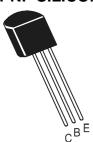


TÜV MANAGEMENT SERVICE SHATES

An ISO/TS16949 and ISO 9001 Certified Company

PNP SILICON PLANAR EPITAXIAL TRANSISTORS



BC 307, A, B, C BC 308, A, B, C BC 309, A, B, C

TO-92 Plastic Package

General Purpose Transistors Deisgned For Small Signal Amplification

From DC To Low Radio Frequencies

ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	BC307	BC308	BC309	UNITS
Collector Emitter Voltage	V_{CEO}	45	25	25	V
Collector Base Voltage	V_{CBO}	50	30	30	V
Emitter Base Voltage	V_{EBO}	5	5	5	V
Collector Current Continuous	Ic		100		mA
Power Dissipation@ Ta=25°C	P_D		350		mW
Derate Above 25°C			2.8		mW/°C
Power Dissipation@ Tc=25°C	P_D		1		W
Derate Above 25°C			8		mW/°C
Operating And Storage Junction	T_{j},T_{stg}		55 to +15	0	°C
Temperature Range					
THERMAL RESISTANCE					
Junction to ambient	$R_{th(j-a)}$		357		°C/W
Junction to case	$R_{th(j-c)}$		125		°C/W

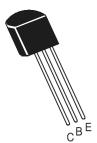
PNP SILICON PLANAR EPITAXIAL TRANSISTORS

BC 307, A, B, C BC 308, A, B, C BC 309, A, B, C

TO-92 Plastic Packa e

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)								
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS		
Collector Emitter Breakdown	BV_CEO	$I_C=2mA,I_B=0$						
Voltage								
BC307			45			V		
BC308, BC309			25			V		
Emitter Base Breakdown Voltage	BV_EBO	I _E =100uA, I _C =0	5			V		
Collector Emitter Leakage Current								
BC307	$I_{\sf CES}$	V_{CES} =50V, V_{BE} =0			15	nA		
BC308, BC309		$V_{CES} = 30V$, $V_{BE} = 0$			15	nA		
BC307		$V_{CES} = 50V$, $V_{BE} = 0$,			4	μΑ		
		T _A =125°C				•		
BC308, BC309		$V_{CES} = 30V$, $V_{BE} = 0$,			4	μΑ		
		T _A =125°C						
DC Current Gain								
Α	h_{FE}	Ic=10uA,VcE=5V		90				
В				150				
C				270				
BC307, BC308, BC309		$I_C=2mA,V_{CE}=5V$	120		800			
Α			120	170	220			
В			200	290	460			
С			420	500	800			
А		I _C =2mA,V _{CE} =5V*		120				
В				180				
С				300				
Collector Emitter Saturation	V _{CE} (sat)	$I_C=10mA, I_B=0.5mA$		0.10	0.3	V		
Voltage		$I_C=100mA,I_B=5mA$		0.25		V		
Base Emitter Saturation Voltage	V _{BE} (sat)	$I_C=10mA,I_B=0.5mA$		0.7		V		
		$I_C=100mA,I_B=5mA$		1.0		V		
Base Emitter On Voltage	V _{BE} (on)	$I_C=2mA, V_{CE}=5V$	0.55	0.62	0.7	V		

SILICON PLANAR EPITAXIAL TRANSISTORS



BC 307, A, B, C BC 308, A, B, C BC 309, A, B, C

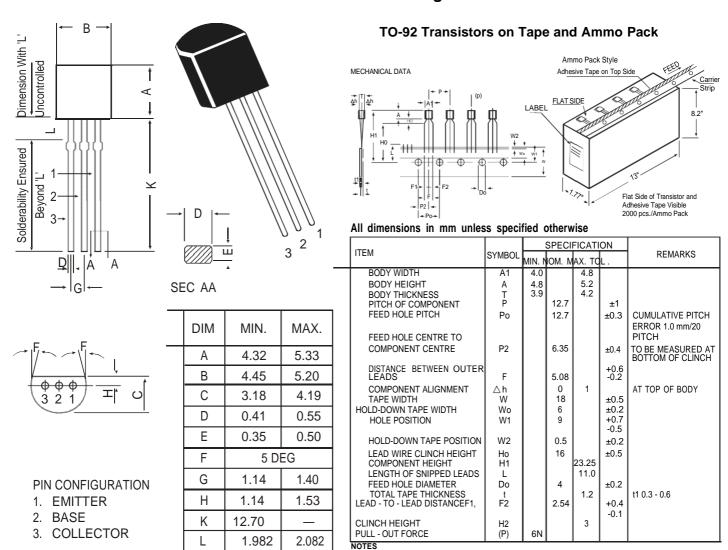
TO-92 Plastic Package

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBO	TEST CONDITION	MIN TYP	MAX	UNITS
DYNAMIC CHARACTERISTICS					
Transition Frequency	f⊤	I _C =10mA, V _{CE} =5V			
BC307	•	f=50MHz	280		MHz
BC308	}		320		MHz
BC309)		360		MHz
Collector Base Capacitance	C_cbo	V _{CB} =10V, I _E =0		6	pF
Noise Figure		f=1MHz			
BC 309	NF	$I_C=0.2mA$, $V_{CE}=5V$	2	4	dB
		Rg=2K Ω f=30Hz to 15KHz			
BC307, BC308	}	f =1KHz, B=200Hz	2	10	dB
BC309)		2	4	dB
		$R_S=2K\Omega f=30Hz$			
		to 15KHz			

TO-92 Plastic Package

TO-92 Plastic Package



All diminsions in mm.

- MAXIMUM ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.
 MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20
- HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO EXPOSURE OF ADHESIVE.
- NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.
 A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.
- SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

Notes

BC 307, A, B, C BC 308, A, B, C BC 309, A, B, C

TO-92 Plastic Package

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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